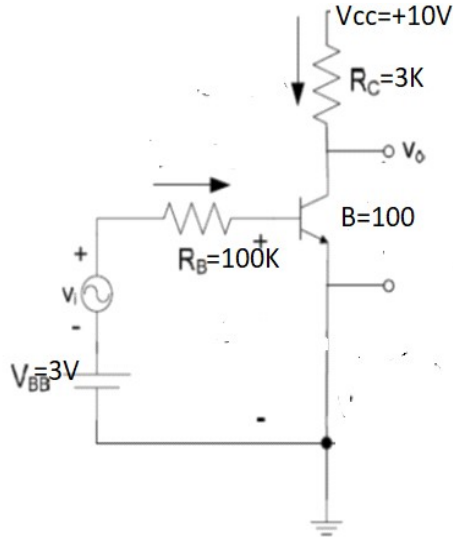


CONTINUOUS INTERNAL EVALUATION- 1

Dept:EC	Sem / Div:IV A&B	Sub:Analog Circuits	S Code:18EC42
Date:24/05/2021	Time: 3:00-4:30 pm	Max Marks: 50	Elective:N
Note: Answer any 2 full questions, choosing one full question from each part.			

Q N	Questions	Marks	RBT	COs
PART A				
1	a Explain the design constraints of a classical discrete-circuit biasing arrangement with circuit and relevant equations. How does RE provide a negative feedback action to stabilize the bias current?	9	L2	CO1
	b Explain the three basic configurations of MOSFET	6	L2	CO1
	c Design the classical discrete circuit bias network to establish a current $I_E = 1 \text{ mA}$ using a power supply $V_{CC} = +12 \text{ V}$. The transistor is specified to have a nominal β value of 100. calculate the expected range of I_E if the transistor used has β in the range of 50 to 150. Express the range of I_E as a percentage of the nominal value ($I_E = 1 \text{ mA}$) obtained for $\beta = 100$. do it for both the designs i.e, design 1: considering voltage divider current as $0.1I_E$. For design 2: considering voltage divider current as I_E	10	L3	CO1
OR				
2	a With a neat circuit diagram and ac equivalent circuit derive the expressions for R_{in} , A_{vo} , A_v and R_o for common source amplifier	10	L2	CO1
	b Considering the conceptual circuit of common emitter configuration, derive the expressions for g_m , r_{π} , and r_e . Draw the hybrid $-\pi$ model of a transistor.	9	L2	CO1
	c Derive the Voltage gain with respect to small signal operation of BJT. Also obtain the relation between emitter and base resistance.	6	L3	CO1
PART B				
3	a A CS amplifier utilizes a MOSFET biased at $I_D = 0.25 \text{ mA}$ with $V_{OV} = 0.25 \text{ V}$ and $R_D = 20 \text{ k}\Omega$. The device has $V_A = 50 \text{ V}$. The amplifier is fed with a source having $R_{sig} = 100 \text{ k}\Omega$, and a $20\text{-k}\Omega$ load is connected to the output. Find R_{in} , A_{vo} , A_v and R_o and G_V . If to maintain reasonable linearity, the peak of the input sine-wave signal is limited to 10% of $(2V_{OV})$ what is the peak of the sinewave voltage at the output?	10	L3	CO1
	b With a neat circuit diagram and ac equivalent circuit derive the expressions for R_{in} , A_{vo} , A_v and R_o for common source amplifier with source resistance.	10	L2	CO1
	c Compare BJT with MOSFET	5	L2	CO1
OR				
4	a In the circuit shown, find the overall voltage gain $A_v = v_o/v_i$. Assume $\beta = 100$. Draw the dc equivalent circuit. Also write the small signal equivalent circuit using hybrid- π model	10	L3	CO1

CONTINUOUS INTERNAL EVALUATION- 1



b A BJT having $\beta=100$ is biased at a DC collector current of 1mA. Find the value of g_m , r_e and r_{π} at the bias point

6

L3

CO1

c A BJT CE amplifier is biased to operate at a constant collector current , V_{BE} is adjusted to yield a dc collector current of 1 mA. Let $V_{CC} = 15$ V, $R_C = 12$ k Ω , and $\beta = 80$. Find the voltage gain V_{ce}/V_{be} . If $v_{be} = 0.002 \sin \omega t$ volt, find $v_C(t)$ and $i_B(t)$.

9

L3

CO1